

**S/N Unknown**

**PATENT**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant:	Mark L. Jenson et al.	Examiner:	Brian L Mutschler
Serial No.:	Unknown	Group Art Unit:	Unknown
Filed:	Herewith	Docket:	1327.007US2
Title:	INTEGRATED CAPACITOR-LIKE BATTERY AND ASSOCIATED METHOD (Continuation of U.S. Serial No. 09/815,621 filed March 23, 2001)		

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**INFORMATION DISCLOSURE STATEMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

In compliance with the duty imposed by 37 C.F.R. § 1.56, and in accordance with 37 C.F.R. §§ 1.97 *et. seq.*, the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified patent application. Applicants respectfully request that this Information Disclosure Statement be entered and the documents listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to the provisions of MPEP 609, Applicants request that a copy of the 1449 form, initialed as being considered by the Examiner, be returned to the Applicants with the next official communication.

Pursuant to 37 C.F.R. §1.97(b), it is believed that no fee or statement is required with the Information Disclosure Statement. However, if an Office Action on the merits has been mailed, the Commissioner is hereby authorized to charge the required fees to Deposit Account No. 19-0743 in order to have this Information Disclosure Statement considered.

Pursuant to 37 C.F.R. §1.98(d), copies of most of the listed documents are not provided as these references were previously cited by or submitted to the U.S. Patent Office in connection with Applicants' prior U.S. application, Serial No. 09/815621, filed on March 23, 2001, which is relied upon for an earlier filing date under 35 U.S.C. §120.

Attached are copies of documents which were not earlier cited in parent application Serial No. 09/815621. These documents are also listed on the attached 1449 form.

INFORMATION DISCLOSURE STATEMENT

Serial No :Unknown

Filing Date: Herewith

Title: INTEGRATED CAPACITOR-LIKE BATTERY AND ASSOCIATED METHOD

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The Examiner is invited to contact the Applicants' Representative at the below-listed telephone number if there are any questions regarding this communication.

Respectfully submitted,

MARK L. JENSON ET AL.

By their Representatives,

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Substitute for form 1449A/PTO

**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**  
(Use as many sheets as necessary)

Complete if Known

<b>Application Number</b>	Unknown
<b>Filing Date</b>	Even Date Herewith
<b>First Named Inventor</b>	Jenson, Mark
<b>Group Art Unit</b>	Unknown
<b>Examiner Name</b>	Mutschler, Brian

Sheet 1 of 6

Attorney Docket No: 1327.007US2

**US PATENT DOCUMENTS**

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EXAMINER

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Substitute Disclosure Statement Form (PTO-1449)

\* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. † Applicant's unique citation designation number (optional) ‡ Applicant is to place a check mark here if English language Translation is attached

Substitute for form 1449A/PTO <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> <i>(Use as many sheets as necessary)</i>	Complete if Known	
	<b>Application Number</b>	Unknown
	<b>Filing Date</b>	Even Date Herewith
	<b>First Named Inventor</b>	Jenson, Mark
	<b>Group Art Unit</b>	Unknown
	<b>Examiner Name</b>	Mutschler, Brian
Sheet 2 of 6	Attorney Docket No: 1327.007US2	

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EXAMINER

DATE CONSIDERED

Substitute for form 1449A/PTO <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> <i>(Use as many sheets as necessary)</i>	Complete if Known <table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="width: 50%;"><b>Application Number</b></td> <td>Unknown</td> </tr> <tr> <td><b>Filing Date</b></td> <td>Even Date Herewith</td> </tr> <tr> <td><b>First Named Inventor</b></td> <td>Jenson, Mark</td> </tr> <tr> <td><b>Group Art Unit</b></td> <td>Unknown</td> </tr> <tr> <td><b>Examiner Name</b></td> <td>Mutschler, Brian</td> </tr> </table>	<b>Application Number</b>	Unknown	<b>Filing Date</b>	Even Date Herewith	<b>First Named Inventor</b>	Jenson, Mark	<b>Group Art Unit</b>	Unknown	<b>Examiner Name</b>	Mutschler, Brian
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Sheet 4 of 6	Attorney Docket No: 1327.007US2										

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EXAMINER

DATE CONSIDERED

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<b>First Named Inventor</b>	Jenson, Mark
<b>Group Art Unit</b>	Unknown
<b>Examiner Name</b>	Mutschler, Brian

Sheet 3 of 6

Attorney Docket No: 1327.007US2

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**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T <sup>2</sup>
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EXAMINER

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Substitute Disclosure Statement Form (PTO-1449)

\* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 809. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. 1 Applicant's unique citation designation number (optional) 2 Applicant is to place a check mark here if English language Translation is attached

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<b>Group Art Unit</b>	Unknown
<b>Examiner Name</b>	Mutschler, Brian

Sheet 5 of 6

Attorney Docket No: 1327.007US2

**OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
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EXAMINER

DATE CONSIDERED

Substitute Disclosure Statement Form (PTO-1449)

\* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 809. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. 1 Applicant's unique citation designation number (optional) 2 Applicant is to place a check mark here if English language Translation is attached

Substitute for form 1449A/PTO <b>INFORMATION DISCLOSURE                  STATEMENT BY APPLICANT</b> <i>(Use as many sheets as necessary)</i>	<i>Complete if Known</i>	
	<b>Application Number</b>	Unknown
	<b>Filing Date</b>	Even Date Herewith
	<b>First Named Inventor</b>	Jenson, Mark
	<b>Group Art Unit</b>	Unknown
	<b>Examiner Name</b>	Mutschler, Brian
Sheet 6 of 6	Attorney Docket No: 1327.007US2	

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**DATE CONSIDERED**